



#### P-CHANNEL ENHANCEMENT MODE MOSFET

## **Product Summary**

Ī	BV <sub>DSS</sub>	R <sub>DS(ON)</sub>	Package	I <sub>D</sub> T <sub>A</sub> = +25°C
I	-20V	110mΩ @ V <sub>GS</sub> = -4.5V	SOT23	-2.6A
	-200	225mΩ @ V <sub>GS</sub> = -2.5V	30123	-2.0A

# Description

This new generation MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

# Applications

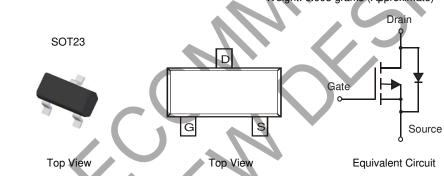
- General Purpose Interfacing Switch
- Power Management Functions

### **Features**

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

# Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 3
- Terminal Connections: See Diagram
- Weight: 0.008 grams (Approximate)



### Ordering Information (Note 5)

Part Number	Qualification	Case	Packaging
DMP2225L-7	Standard	SOT-23	3000/Tape & Reel
DMP2225LQ-7	Automotive	SOT-23	3000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

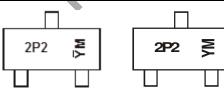
2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product\_grade\_definitions/.

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

# Marking Information



2P2 = Product Type Marking Code YM = Date Code Marking for SAT (Shanghai Assembly/ Test site) YM = Date Code Marking for CAT (Chengdu Assembly/ Test site)

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Y or \overline{Y} = Year (ex: E = 2017)
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M = Month (ex: 9 = September)

Date	Code	Key

Notes:

Shanghai A/T Site

	Chengdu	A/T	Site
Code Kev			

Year	2008		2009	~		2017	2018		2019	2020	)	2021
Code	V		W	~		E	F		G	Н		I
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



# **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteri	stic		Symbol	Value	Unit
Drain-Source Voltage			V <sub>DSS</sub>	-20	V
Gate-Source Voltage			V <sub>GSS</sub>	±12	V
Continuous Drain Current (Note 6)	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	Ι <sub>D</sub>	-2.6 -2	А
Pulsed Drain Current (Note 7)			I <sub>DM</sub>	8	А

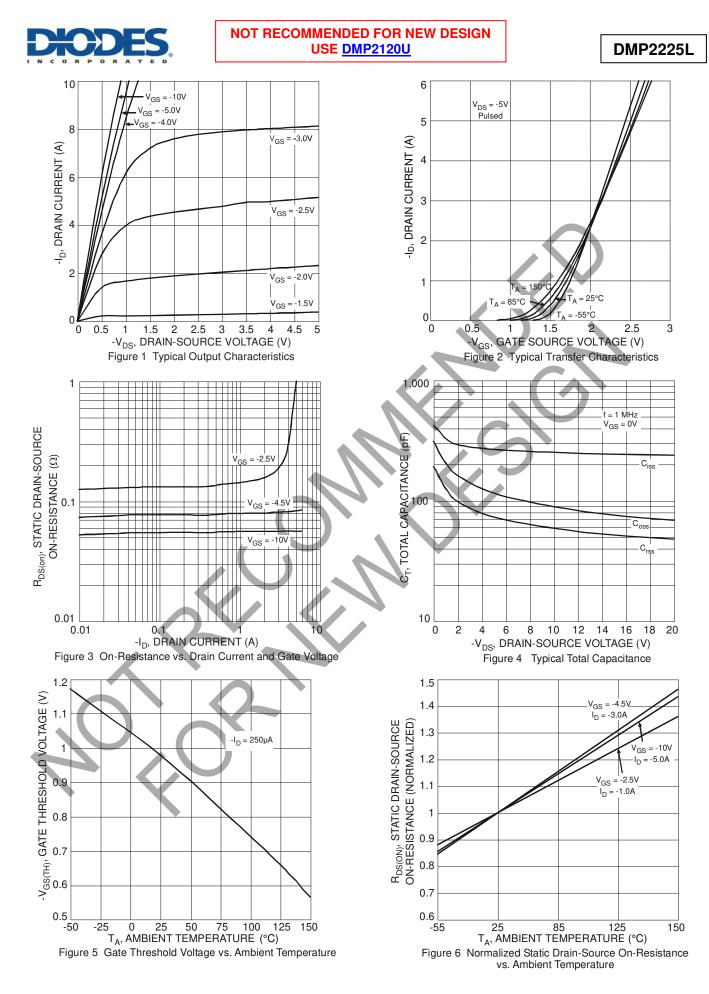
# **Thermal Characteristics**

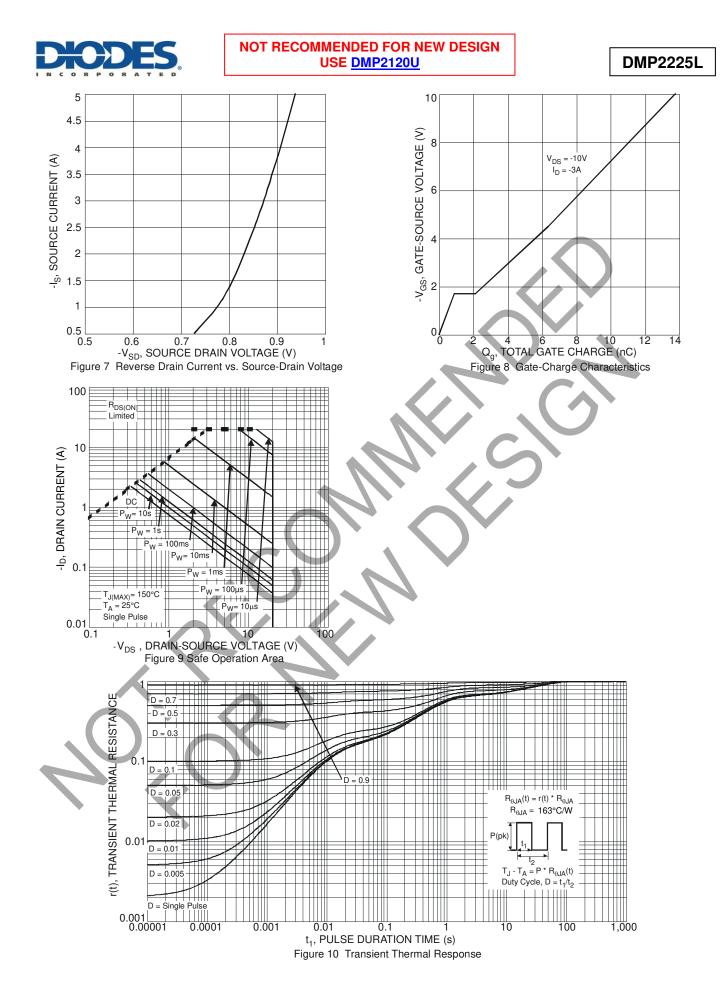
Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 6)	P <sub>D</sub>	1.08	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 6)	R <sub>θJA</sub>	115	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	0°

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

			-				
Characteristic	Symbol	Min	Тур	Max 🔪	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-20		—	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS	-		-800	nA	$V_{DS} = -20V, V_{GS} = 0V$	
On-State Drain Current	I <sub>D(ON)</sub>	-6 -3			А	$V_{DS} \le -5V, V_{GS} = -4.5V$ $V_{DS} \le -5V, V_{GS} = -2.5V$	
Gate-Source Leakage	IGSS		—	±80	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)				•			
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-0.45		-1.25	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>		80 165	110 225	mΩ	$V_{GS} = -4.5V, I_D = -2.6A$ $V_{GS} = -2.5V, I_D = -2.0A$	
Forward Transfer Admittance	Y <sub>fs</sub>		4	_	S	$V_{DS} = -5V, I_D = -2.6A$	
Diode Forward Voltage (Note 7)	V <sub>SD</sub>	V-		-1.26	V	$V_{GS} = 0V, I_{S} = -2.6A$	
DYNAMIC CHARACTERISTICS (Note 9)		•					
Input Capacitance	C <sub>iss</sub>	_	250	—	pF		
Output Capacitance	Coss	_	88	—	pF	V <sub>DS</sub> = -10V, V <sub>GS</sub> = 0V f = 1.0MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	_	58	_	pF		
Gate Resistance	Rq	_	12	16	Ω	$V_{GS} = 0V, V_{DS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	_	4.3	5.3			
Gate-Source Charge	Q <sub>gs</sub>	—	0.9	_	nC	$V_{GS} = -4.5V, V_{DS} = -10V,$	
Gate-Drain Charge	Q <sub>gd</sub>	_	2.1	_		I <sub>D</sub> = -2.7A	

 6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
7. Repetitive rating, pulse width limited by junction temperature.
8. Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to production testing. Notes:

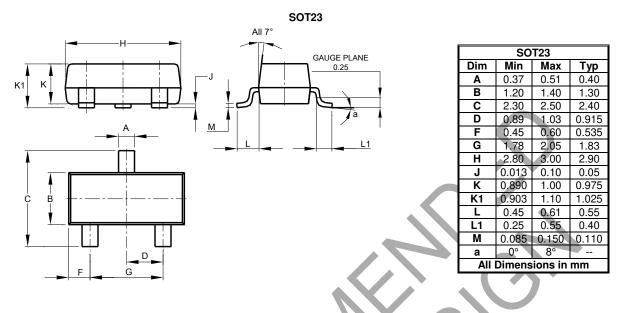






# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

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Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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